2SC4420

Silicon NPN triple diffusion planar type

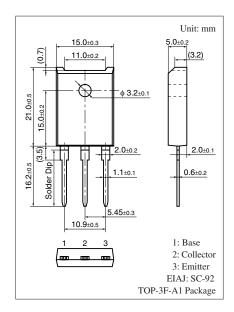
For high breakdown voltage high-speed switching

Features

- High-speed switching
- \bullet High collector-base voltage (Emitter open) V_{CBO}
- Wide safe operation area
- \bullet Satisfactory linearity of forward current transfer ratio h_{FE}
- · Full-pack package which can be installed to the heat sink with one screw

Absolute Maximum Ratings $T_C = 25^{\circ}C$

| Parameter | Symbol | Rating | Unit |
|---------------------------------------|------------------|-------------|------|
| Collector-base voltage (Emitter open) | V _{CBO} | 900 | V |
| Collector-emitter voltage (E-B short) | V _{CES} | 900 | V |
| Collector-emitter voltage (Base open) | V _{CEO} | 800 | V |
| Emitter-base voltage (Collector open) | V _{EBO} | 7 | V |
| Base current | IB | 1 | А |
| Collector current | I _C | 3 | А |
| Peak collector current | I _{CP} | 5 | А |
| Collector power dissipation | P _C | 70 | W |
| $T_a = 25^{\circ}C$ | | 3.0 | |
| Junction temperature | Tj | 150 | °C |
| Storage temperature | T _{stg} | -55 to +150 | °C |

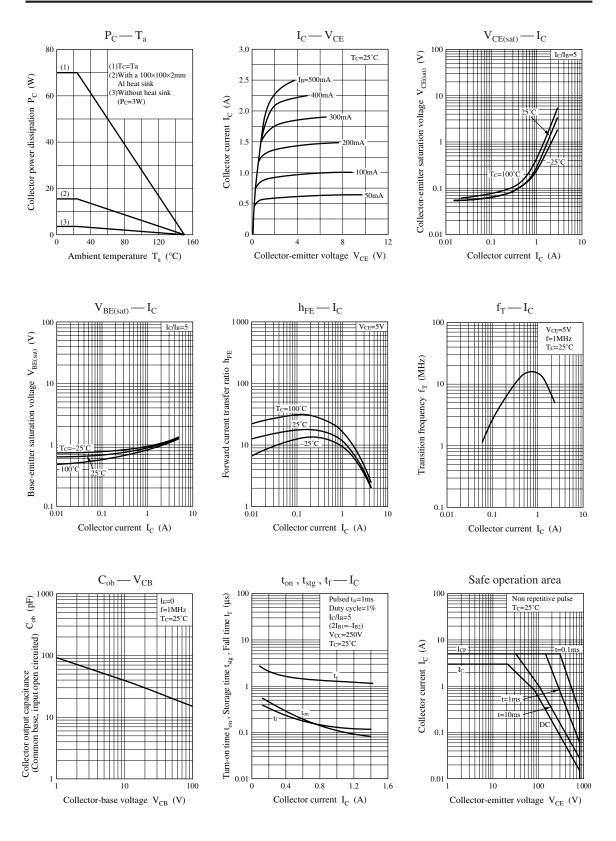


Electrical Characteristics $T_C = 25^{\circ}C \pm 3^{\circ}C$

| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|--|----------------------|---|-----|-----|-----|------|
| Collector-emitter voltage (Base open) | V _{CEO} | $I_{\rm C} = 10 \text{ mA}, I_{\rm B} = 0$ | 800 | | | V |
| Collector-base cutoff current (Emitter open) | I _{CBO} | $V_{CB} = 900 \text{ V}, I_E = 0$ | | | 50 | μΑ |
| Emitter-base cutoff current (Collector open) | I _{EBO} | $V_{EB} = 7 V, I_C = 0$ | | | 50 | μΑ |
| Forward current transfer ratio | h _{FE1} | $V_{CE} = 5 V, I_C = 0.1 A$ | 8 | | | _ |
| | h _{FE2} | $V_{CE} = 5 \text{ V}, I_C = 0.8 \text{ A}$ | 6 | | | |
| Collector-emitter saturation voltage | V _{CE(sat)} | $I_{\rm C} = 0.8 \text{ A}, I_{\rm B} = 0.16 \text{ A}$ | | | 1.5 | V |
| Base-emitter saturation voltage | V _{BE(sat)} | $I_{\rm C} = 0.8 \text{ A}, I_{\rm B} = 0.16 \text{ A}$ | | | 1.5 | V |
| Transition frequency | f _T | $V_{CE} = 5 \text{ V}, I_C = 0.15 \text{ A}, f = 1 \text{ MHz}$ | | 10 | | MHz |
| Turn-on time | t _{on} | I _C = 0.8 A | | | 0.7 | μs |
| Storage time | t _{stg} | $I_{B1} = 0.16 \text{ A}, I_{B2} = -0.32 \text{ A}$ | | | 2.5 | μs |
| Fall time | t _f | $V_{CC} = 250 \text{ V}$ | | | 0.3 | μs |

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

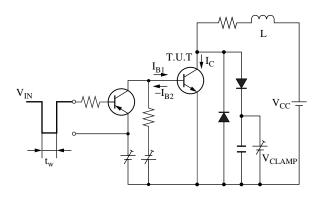
Panasonic



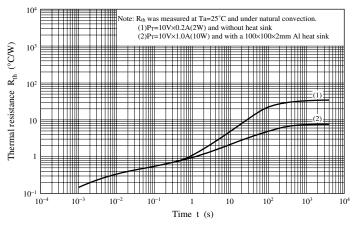
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Safe operation area (Reverse bias)

Safe operation area (Reverse bias) measurement circuit







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